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IGBT Gate Drive Unit VLA592-01R



Mar.2017



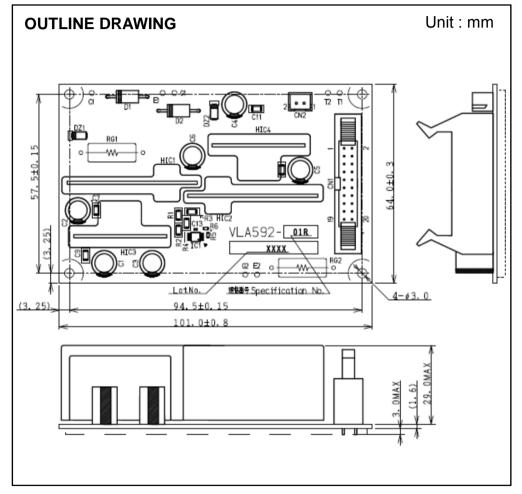
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FEATURE

- >Possible to mount on the IGBT package (2 in 1 package)
- >Built in the isolated DC-DC converter for gate drive
- >Built in short circuit protection (with soft shut down)
- >Electrical isolation voltage is 2500Vrms (for 1 minute)
- >One way power supply system for drivers and input signal (VD=15V)

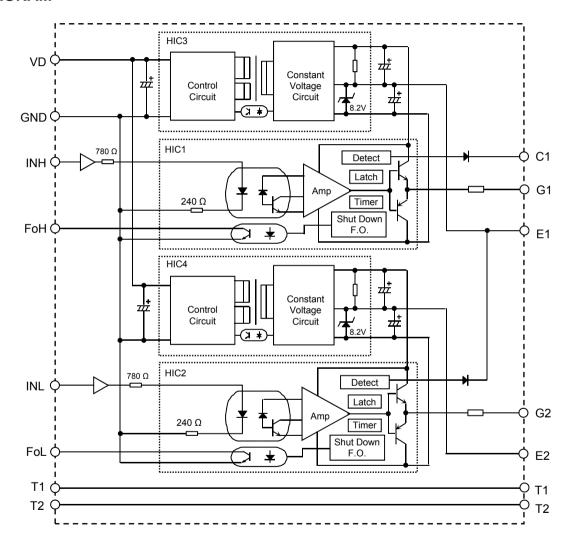
TARGETED IGBT MODULES

VCES = 650V series ~ 600A class VCES = 1200V series ~ 450A class



BLOCK DIAGRAM

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MAXIMUM RATINGS

(unless otherwise noted, Ta=25C)

Symbol	Parameter	Conditions	Ratings	Unit
VD	Supply voltage	DC	15.75	V
VI	Input signal voltage	Applied between GND - INH,INL	19	V
IOHP Coto poels surrent		Dulas width Ove	-5	Α
IOLP	Gate peak current	Pulse width 2us	5	Α
Viso	Isolation voltage	Sine wave voltage 60Hz, for 1min	2500	Vrms
Topr	Operating temperature	No condensation allowable	-20 ~ 70	deg C
Tstg	Storage temperature	No condensation allowable	-25 ~ 85	deg C
IFo	Fo pin output sink current	-	10	mA
VFo	Fo pin voltage	Applied between GND – FoH,FoL	50	V
Idrive	Gate drive current	Gate average current (Per one circuit)	circuit) 83	

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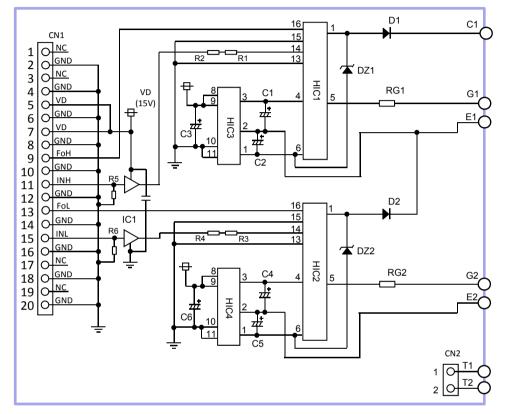
ELECTRICAL CHARACTERISTICS

(unless otherwise noted, Ta=25C, VD=15V)

Symbol	Parameter	Conditions	Limits			Unit
Cymbol		Conditions		Тур	Max	J Silic
VD	Supply voltage	Recommended range	14.25	15	15.75	V
f	Switching frequency	Recommended range	-	-	20	kHz
IFo	Fo output current	Recommended range	-	-	5	mA
RG	Gate resistance	-	-	-	-	Ω
VI_H	Input signal high threshold	-	1.8	2.1	2.4	V
VI_L	Input signal low threshold	-	0.9	1.2	1.5	V
VOH	Plus bias voltage	-	14.5	16.0	17.5	V
VOL	Minus bias voltage	-	-9.0	-8.0	-7.0	V
tPLH	"L-H" propagation time	VI = 15V	0.2	0.45	0.8	us
tPHL	"H-L" propagation time	VI = 15V	0.2	0.4	0.7	us
t_timer	Timer	Between start and clear (under input signal "OFF")	1	1.4	2	ms
td_Fo	Fault out delay time	IFo=2.5mA	-	6.5	10	us
VSC	SC detect collector voltage	IGBT collector voltage	15	-	-	V



INNER CIRCUIT



Main parts list (Reference) HIC1,2 VLA520-01R **ISAHAYA** HIC3,4 VLA106-15252 **ISAHAYA** UCC27524A DZ1,2 30V, 500mW class D1,2 RP1H SanKen CN1 3428-6002LCPL ЗМ B2B-XH-A CN2 **JST** R1,2,3,4 390 ohm 1/4W R5,6 10k ohm 1/10W RG1,2 3W

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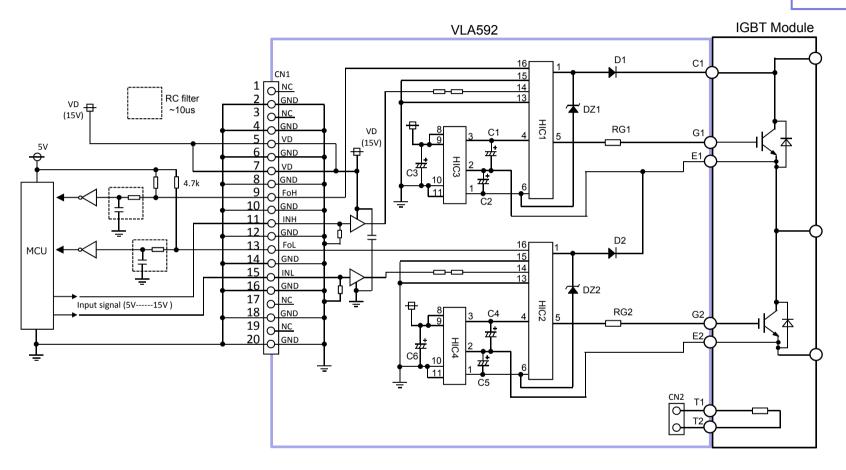
CN1					
PinN.o.	Pin name				
1	NC				
2	GND				
3	NC				
4	GND				
5	VD				
6	GND				
7	VD				
8	GND				
9	FoH				
10	GND				
11	INH				
12	GND				
13	FoL				
14	GND				
15	INL				
16	GND				
17	NC				
18	GND				
19	NC				
20	GND				

CN2				
Pin N.o.	Pin name			
1	T1			
2	T2			



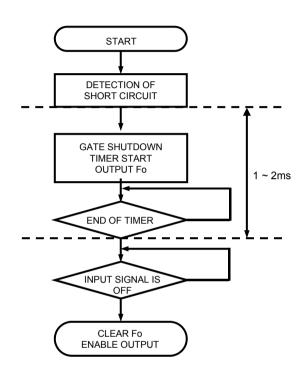
APPLICATION EXAMPLE

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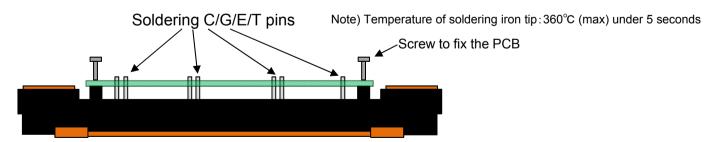
OPERATION FLOW ON DETECTING SHORT CIRCUIT

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- (1)In case the gate signal is "ON" and the collector voltage is high, the gate driver will recognize the circuit as short circuit and immediately reduce the gate voltage.(Soft shut down) Besides, put out an Fo sign which inform that protection circuit is operating.
- (2) The protection circuit return to ordinary condition if input signal is OFF when the predetermined time(1~2ms) passed. (OFF period is needed more than 40us.)

INSTALLATION OF THE PCB ON IGBT MODULE





Keep safety first in your circuit designs!

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